MC1489, MC1489A

Quad Line EIA-232D Receivers

The MC1489 monolithic quad line receivers are designed to interface data terminal equipment with data communications equipment in conformance with the specifications of EIA Standard No. EIA−232D.

Features

- Input Resistance − 3.0 k to 7.0 kΩ
- Input Signal Range − ± 30 V
- Input Threshold Hysteresis Built In
- Response Control
  - a) Logic Threshold Shifting
  - b) Input Noise Filtering
- Pb−Free Packages are Available

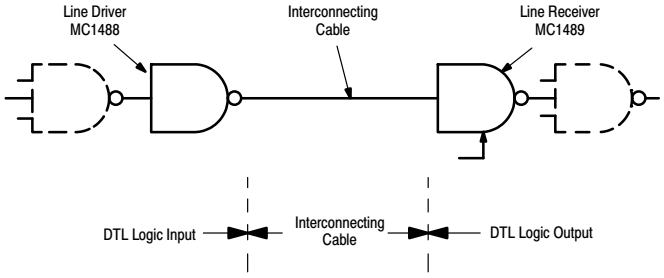
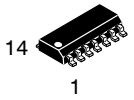


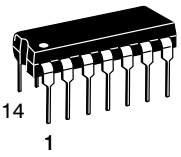
Figure 1. Simplified Application

ON Semiconductor®

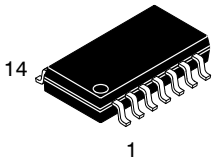
http://onsemi.com



SOIC−14
D SUFFIX
CASE 751A

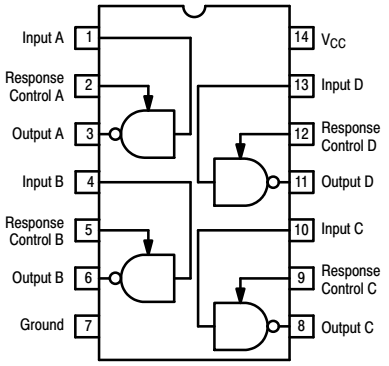


PDIP−14
P SUFFIX
CASE 646



SOEIAJ−14
M SUFFIX
CASE 965

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 9 of this data sheet.

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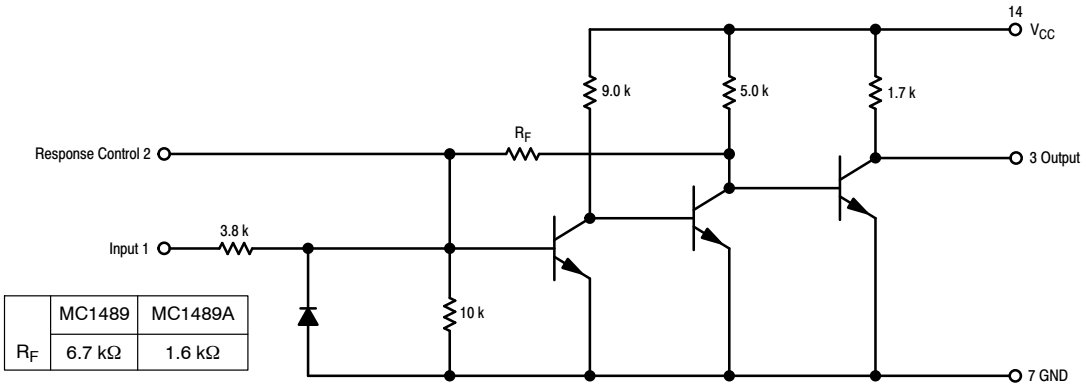


	MC1489	MC1489A
R_F	6.7 kΩ	1.6 kΩ

Figure 2. Representative Schematic Diagram
(1/4 of Circuit Shown)

MAXIMUM RATINGS (T_A = + 25°C, unless otherwise noted)

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}	10	Vdc
Input Voltage Range	V_{IR}	± 30	Vdc
Output Load Current	I_L	20	mA
Power Dissipation (Package Limitation, SOIC−14 and Plastic Dual In−Line Package) Derate above T_A = + 25°C	P_D $1/\theta_{JA}$	1000 6.7	mW mW/°C
Operating Ambient Temperature Range	T_A	0 to + 75	°C
Storage Temperature Range	T_{stg}	− 65 to + 175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

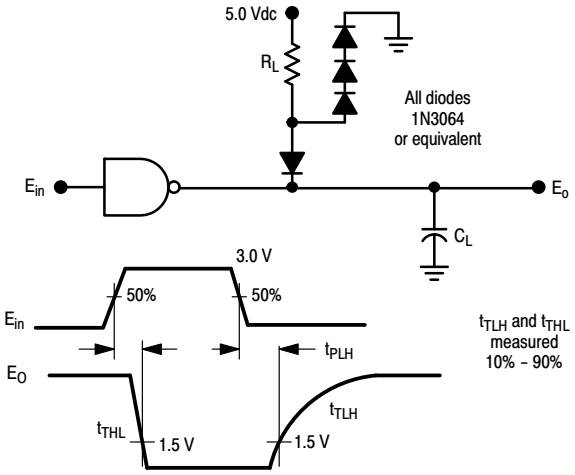
ELECTRICAL CHARACTERISTICS (Response control pin is open.) (V_{CC} = + 5.0 Vdc ± 10%, T_A = 0 to + 75°C, unless otherwise noted)

Characteristics		Symbol	Min	Typ	Max	Unit
Positive Input Current	(V_{IH} = + 25 Vdc) (V_{IH} = + 3.0 Vdc)	I_{IH}	3.6 0.43	− −	8.3 −	mA
Negative Input Current	(V_{IH} = − 25 Vdc) (V_{IH} = − 3.0 Vdc)	I_{IL}	− 3.6 − 0.43	− −	− 8.3 −	mA
Input Turn−On Threshold Voltage (T_A = + 25°C, $V_{OL} \leq$ 0.45 V)	 MC1489 MC1489A	V_{IH}	 1.0 1.75	 − 1.95	 1.5 2.25	Vdc
Input Turn−Off Threshold Voltage (T_A = + 25°C, $V_{OH} \geq$ 2.5 V, I_L = − 0.5 mA)	 MC1489 MC1489A	V_{IL}	 0.75 0.75	 − 0.8	 1.25 1.25	Vdc
Output Voltage High	(V_{IH} = 0.75 V, I_L = − 0.5 mA) (Input Open Circuit, I_L = − 0.5 mA)	V_{OH}	2.5 2.5	4.0 4.0	5.0 5.0	Vdc
Output Voltage Low	(V_{IL} = 3.0 V, I_L = 10 mA)	V_{OL}	−	0.2	0.45	Vdc
Output Short−Circuit Current		I_{OS}	−	− 3.0	− 4.0	mA
Power Supply Current (All Gates "on," I_{out} = 0 mA, V_{IH} = + 5.0 Vdc)		I_{CC}	−	16	26	mA
Power Consumption	(V_{IH} = + 5.0 Vdc)	P_C	−	80	130	mW

SWITCHING CHARACTERISTICS (V_{CC} = 5.0 Vdc ± 1%, T_A = + 25°C, See Figure 3.)

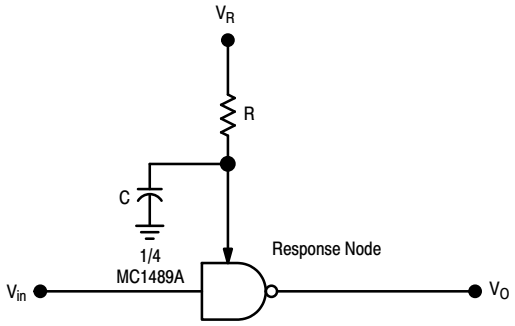
Propagation Delay Time	(R_L = 3.9 kΩ)	t_{PLH}	−	25	85	ns
Rise Time	(R_L = 3.9 kΩ)	t_{TLH}	−	120	175	ns
Propagation Delay Time	(R_L = 390 kΩ)	t_{PHL}	−	25	50	ns
Fall Time	(R_L = 390 kΩ)	t_{THL}	−	10	20	ns

TEST CIRCUITS



C_L = 15 pF = total parasitic capacitance which includes probe and wiring capacitances

Figure 3. Switching Response



C, capacitor is for noise filtering.
R, resistor is for threshold shifting.

Figure 4. Response Control Node

TYPICAL CHARACTERISTICS

(V_{CC} = 5.0 Vdc, T_A = +25°C, unless otherwise noted)

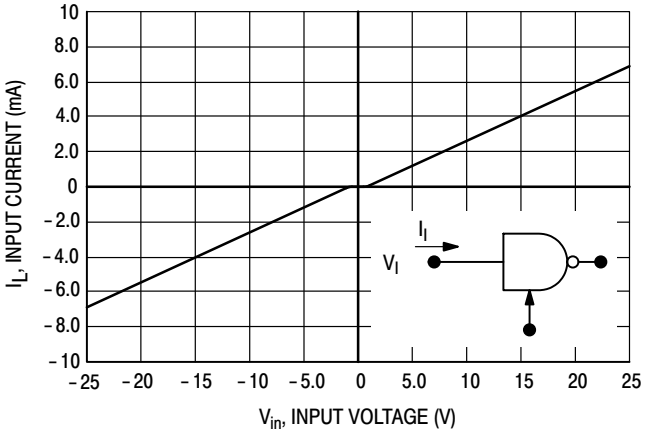


Figure 5. Input Current

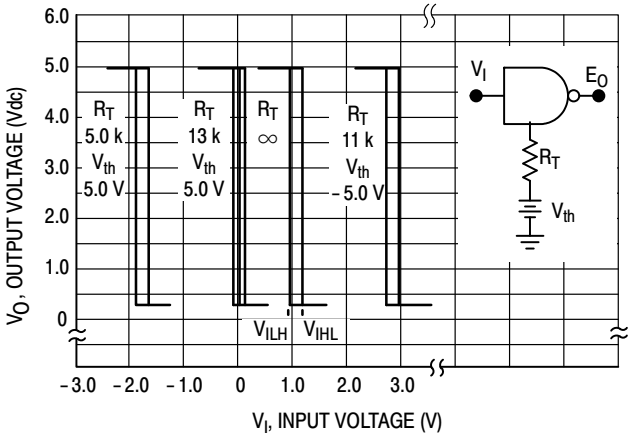


Figure 6. MC1489 Input Threshold Voltage Adjustment

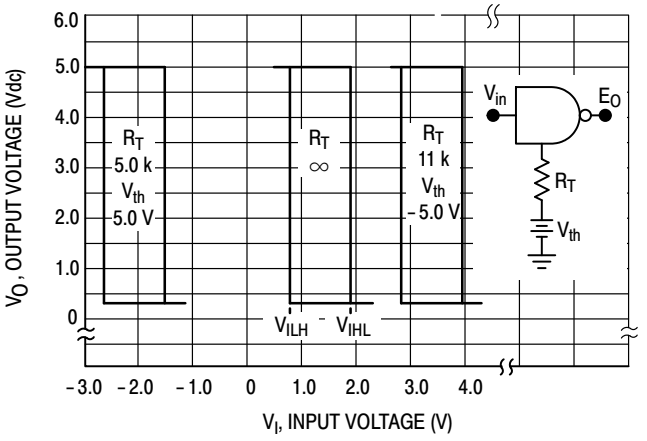


Figure 7. MC1489A Input Threshold Voltage Adjustment

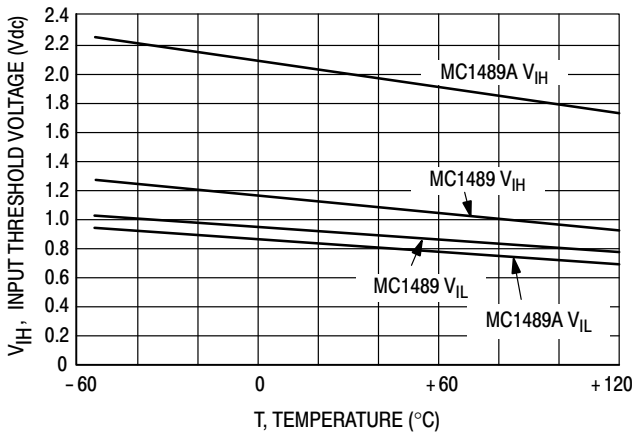


Figure 8. Input Threshold Voltage versus Temperature

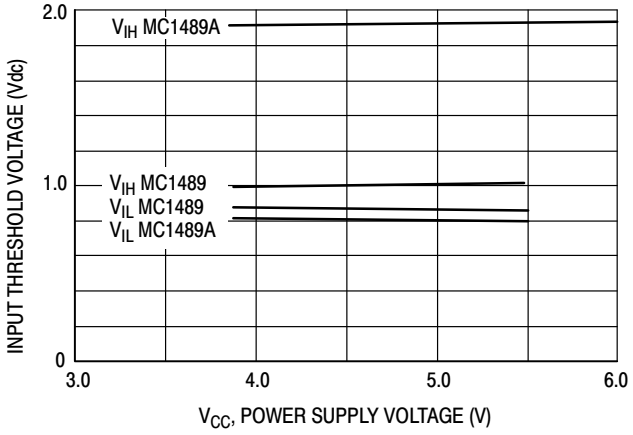


Figure 9. Input Threshold versus Power Supply Voltage

APPLICATIONS INFORMATION

General Information

The Electronic Industries Association (EIA) has released the EIA−232D specification detailing the requirements for the interface between data processing equipment and data communications equipment. This standard specifies not only the number and type of interface leads, but also the voltage levels to be used. The MC1488 quad driver and its companion circuit, the MC1489 quad receiver, provide a complete interface system between DTL or TTL logic levels and the EIA−232D defined levels. The EIA−232D requirements as applied to receivers are discussed herein.

The required input impedance is defined as between 3000 Ω and 7000 Ω for input voltages between 3.0 and 25 V in magnitude; and any voltage on the receiver input in an open circuit condition must be less than 2.0 V in magnitude. The MC1489 circuits meet these requirements with a maximum open circuit voltage of one V_{BE}.

The receiver shall detect a voltage between − 3.0 and −25 V as a Logic “1” and inputs between 3.0 and 25 V as a Logic “0.” On some interchange leads, an open circuit of power “OFF” condition (300 Ω or more to ground) shall be decoded as an “OFF” condition or Logic “1.” For this reason, the input hysteresis thresholds of the MC1489 circuits are all above ground. Thus an open or grounded input will cause the same output as a negative or Logic “1” input.

Device Characteristics

The MC1489 interface receivers have internal feedback from the second stage to the input stage providing input hysteresis for noise rejection. The MC1489 input has typical turn−on voltage of 1.25 V and turn−off of 1.0 V for a typical hysteresis of 250 mV. The MC1489A has typical turn−on of 1.95 V and turn−off of 0.8 V for typically 1.15 V of hysteresis.

Each receiver section has an external response control node in addition to the input and output pins, thereby allowing the designer to vary the input threshold voltage levels. A resistor can be connected between this node and an external power supply. Figures 4, 6 and 7 illustrate the input threshold voltage shift possible through this technique.

This response node can also be used for the filtering of high frequency, high energy noise pulses. Figures 10 and 11 show typical noise pulse rejection for external capacitors of various sizes.

These two operations on the response node can be combined or used individually for many combinations of interfacing applications. The MC1489 circuits are particularly useful for interfacing between MOS circuits and DTL/TTL logic systems. In this application, the input threshold voltages are adjusted (with the appropriate supply and resistor values) to fall in the center of the MOS voltage logic levels (see Figure 12).

The response node may also be used as the receiver input as long as the designer realizes that he may not drive this node with a low impedance source to a voltage greater than one diode above ground or less than one diode below ground. This feature is demonstrated in Figure 13 where two receivers are slaved to the same line that must still meet the EIA−232D impedance requirement.

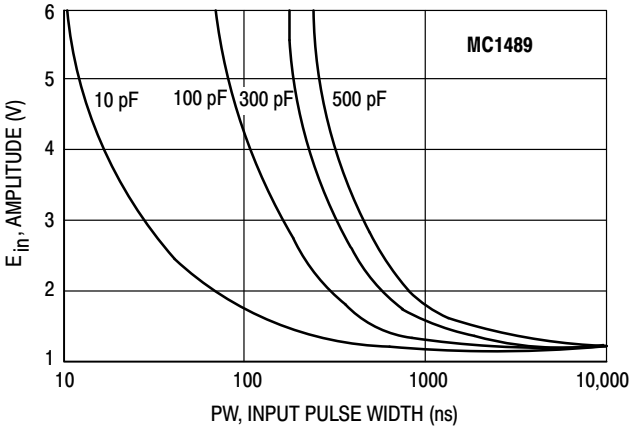


Figure 10. Typical Turn On Threshold versus Capacitance from Response Control Pin to GND

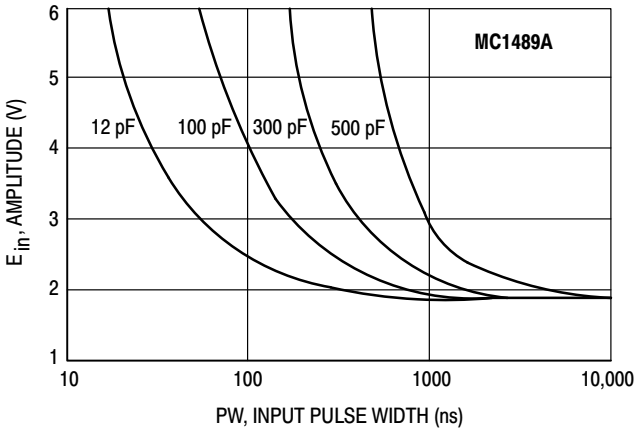


Figure 11. Typical Turn On Threshold versus Capacitance from Response Control Pin to GND

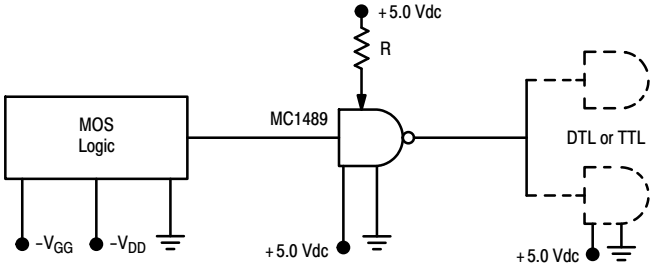


Figure 12. Typical Translator Application − MOS to DTL or TTL

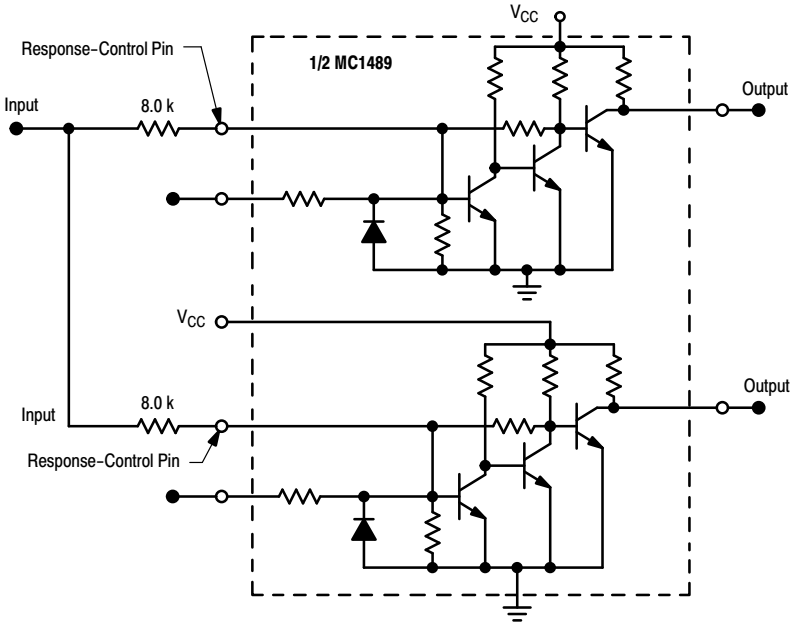


Figure 13. Typical Paralleling of Two MC1489, A Receivers to Meet EIA−232D

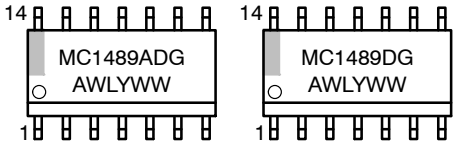
ORDERING INFORMATION

Device	Package	Operating Temperature Range	Shipping†
MC1489D	SOIC−14	T_A = 0 to +75°C	55 Units/Rail
MC1489DG	SOIC−14 (Pb−Free)		
MC1489DR2	SOIC−14		2500 Tape & Reel
MC1489DR2G	SOIC−14 (Pb−Free)		
MC1489AD	SOIC−14		55 Units/Rail
MC1489ADG	SOIC−14 (Pb−Free)		
MC1489ADR2	SOIC−14		2500 Tape & Reel
MC1489ADR2G	SOIC−14 (Pb−Free)		
MC1489P	PDIP−14		25 Units/Rail
MC1489PG	PDIP−14 (Pb−Free)		
MC1489AP	PDIP−14		
MC1489APG	PDIP−14 (Pb−Free)		
MC1489M	SOEIAJ−14		50 Units/Rail
MC1489MG	SOEIAJ−14 (Pb−Free)		
MC1489MEL	SOEIAJ−14		2000 Tape & Reel
MC1489MELG	SOEIAJ−14 (Pb−Free)		
MC1489AM	SOEIAJ−14		50 Units/Rail
MC1489AMG	SOEIAJ−14 (Pb−Free)		
MC1489AMEL	SOEIAJ−14		2000 Tape & Reel
MC1489AMELG	SOEIAJ−14 (Pb−Free)		

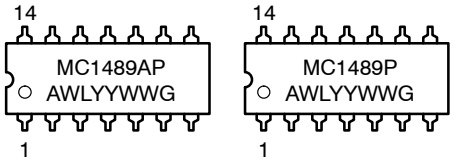
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS

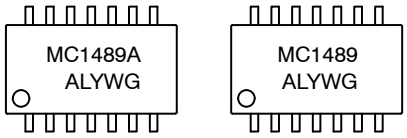
SOIC−14
D SUFFIX
CASE 751A



PDIP−14
P SUFFIX
CASE 646



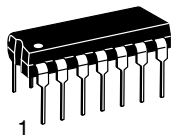
SOEIAJ−14
M SUFFIX
CASE 965



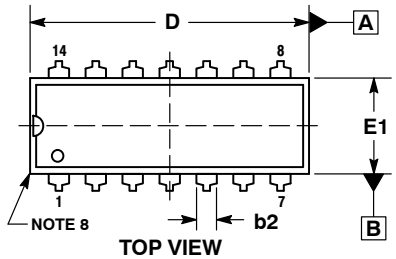
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G	= Pb−Free Package

PDIP−14
CASE 646−06
ISSUE S

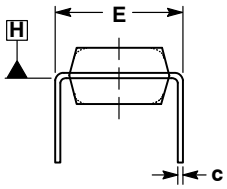
DATE 22 APR 2015



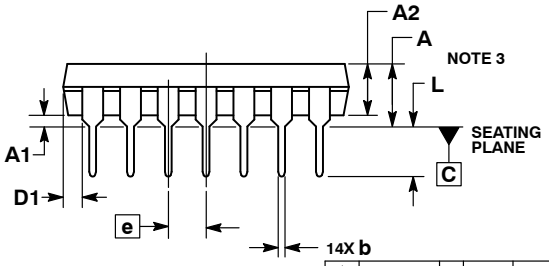
SCALE 1:1



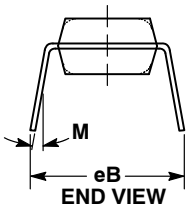
TOP VIEW



END VIEW
WITH LEADS CONSTRAINED
NOTE 5



SIDE VIEW

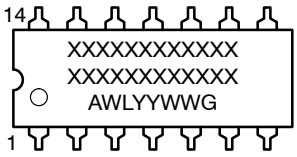


END VIEW
NOTE 6

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS−3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	----	0.210	---	5.33
A1	0.015	----	0.38	---
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52 TYP	
C	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005	----	0.13	---
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	----	0.430	---	10.92
L	0.115	0.150	2.92	3.81
M	----	10°	---	10°

GENERIC
MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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PDIP−14
CASE 646−06
ISSUE S

DATE 22 APR 2015

STYLE 1:
PIN 1. COLLECTOR
2. BASE
3. EMITTER
4. NO CONNECTION
5. EMITTER
6. BASE
7. COLLECTOR
8. COLLECTOR
9. BASE
10. EMITTER
11. NO CONNECTION
12. EMITTER
13. BASE
14. COLLECTOR

STYLE 2:
CANCELLED

STYLE 3:
CANCELLED

STYLE 4:
PIN 1. DRAIN
2. SOURCE
3. GATE
4. NO CONNECTION
5. GATE
6. SOURCE
7. DRAIN
8. DRAIN
9. SOURCE
10. GATE
11. NO CONNECTION
12. GATE
13. SOURCE
14. DRAIN

STYLE 5:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. NO CONNECTION
5. SOURCE
6. DRAIN
7. GATE
8. GATE
9. DRAIN
10. SOURCE
11. NO CONNECTION
12. SOURCE
13. DRAIN
14. GATE

STYLE 6:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 7:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 8:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 9:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

STYLE 10:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 11:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 12:
PIN 1. COMMON CATHODE
2. COMMON ANODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. COMMON ANODE
7. COMMON CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. ANODE/CATHODE
14. ANODE/CATHODE

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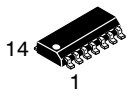

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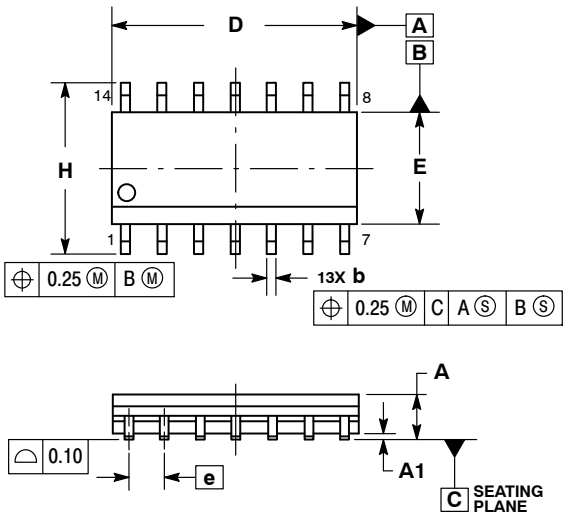
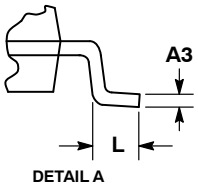
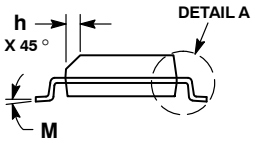
SOIC−14 NB
CASE 751A−03
ISSUE L

DATE 03 FEB 2016



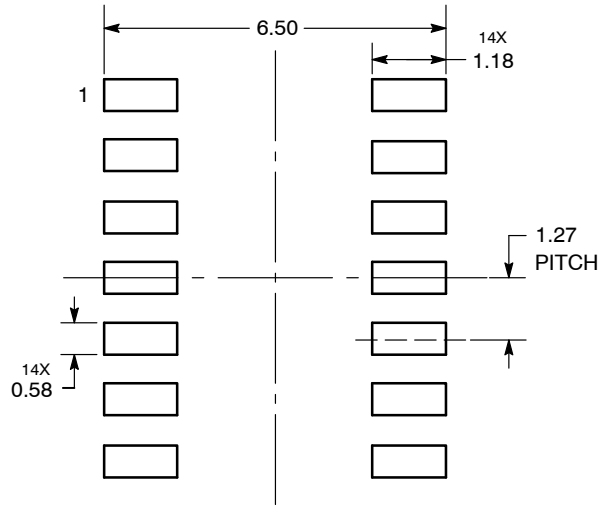




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0 °	7 °	0 °	7 °

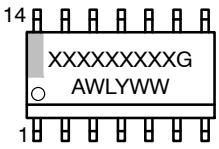
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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SOEIAJ−14
CASE 965−01
ISSUE B

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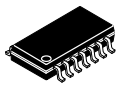

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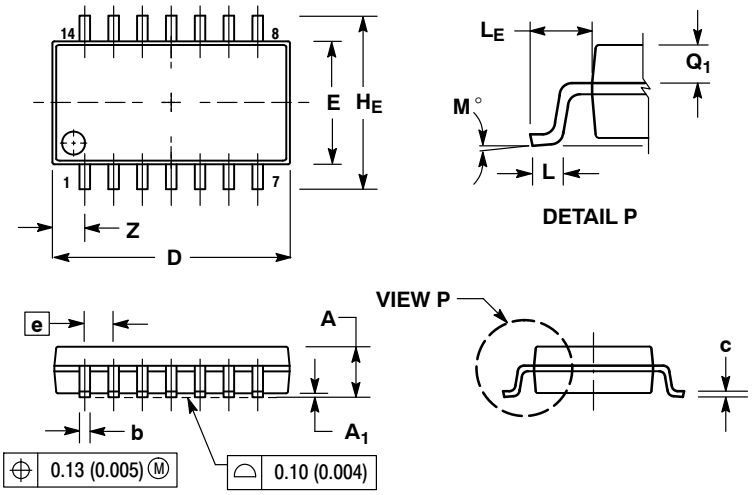

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A_1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.004	0.008
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056

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